2SD1268

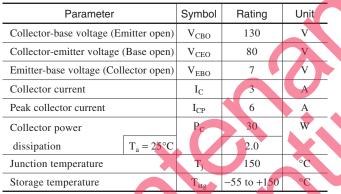
Silicon NPN epitaxial planar type

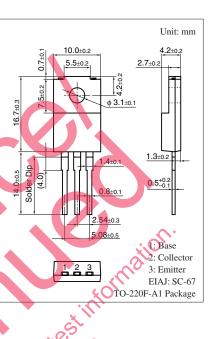
For power switching

Features

- Low collector-emitter saturation voltage V_{CE(sat)}
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw.

Absolute Maximum Ratings $T_C = 25^{\circ}C$





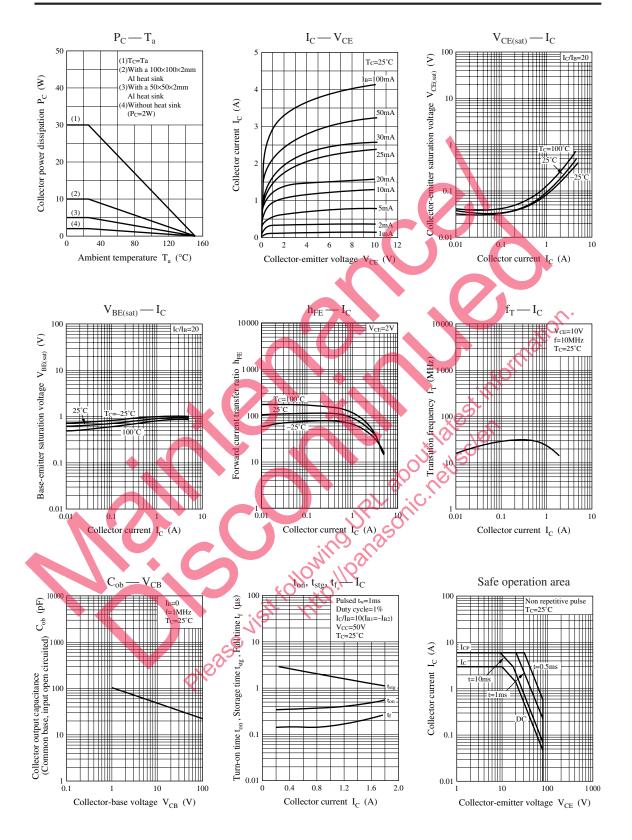
Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

Collector power	Pc	30 W	•	<u>n</u>							
dissipation $T_a = 25^{\circ}C$		2.0	Š								
Junction temperature T _j 150 °C											
Storage temperature T_{xtg} -55 to +150 °C											
Collector power P_c 30 W dissipation $T_a = 25^{\circ}C$ 2.0 Junction temperature T_j 150 °C Storage temperature T_{stg} -55 to +150 °C Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$ P_c 30 W											
Parameter	Symbol	Conditions	Min	Тур	Max	Unit					
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	80			V					
Collector-base cut-off current (Emitter open)	I _{CBO}	$V_{CB} = 100$ V, $I_{E} = 0$			10	μΑ					
Emitter-base cut-off current (Collector open)	I _{EBO}	$V_{EB} \supset V, I_{C} = 0$			50	μΑ					
Forward current transfer ratio	h _{FE1}	$V_{CE} = 2 X, J_C = 0.1 A$	45			—					
	h _{FE2} *	$V_{CE} = 2 V, I_C = 0.5 A$	60		260						
Collector-emitter saturation voltage	Vec(sat)	$I_{\rm C} = 2 \text{ A}, I_{\rm B} = 0.1 \text{ A}$			0.5	V					
Base-emitter saturation voltage	W _{BE(sat)}	$I_{\rm C} = 2 \text{ A}, I_{\rm B} = 0.1 \text{ A}$			1.5	V					
Transition frequency	f _T	$V_{CE} = 10 \text{ V}, I_C = 0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz					
Turn-on time	t _{on}	$I_{C} = 0.5 \text{ A}, I_{B1} = 50 \text{ mA}, I_{B2} = -50 \text{ mA}$		0.5		μs					
Storage time	t _{stg}	$V_{CC} = 50 V$		2.5		μs					
Fall time	t _f			0.15		μs					

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors. 2. *: Rank classification

Rank	R	Q	Р	
h _{FE2}	60 to 120	90 to 180	130 to 260	

Panasonic



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